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View Online at https://aerobasegroup.com/nsn/5961-01-080-1889

Inclosure Material:

Metal

Overall Length:

1.553 inches

Overall Height:

0.380 inches

Overall Width:

1.050 inches

Overall Diameter:

0.875 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

150.0 collector to base voltage/static/emitter open and 90.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage,

static, collector open

Current Rating Per Characteristic:

Between 5.00 amperes source cutoff current and 20.00 amperes source cutoff current

Power Rating Per Characteristic:

140.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

Special Features:

Junction pattern arrangement: npn

Test Data Document:

06509-122024 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

1 case and 2 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

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